

GBU8005 THRU GBU810

Glass Passivated Bridge Rectifiers

Reverse Voltage - 50 to 1000 Volts Forward Current - 8.0 Amperes

Features

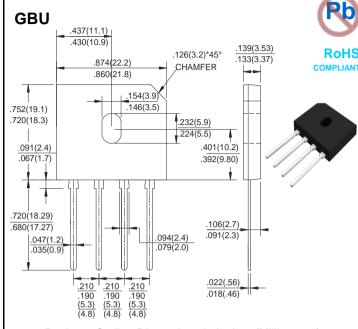
- Glass passivated chip
- Low forward voltage drop
- Ideal for printed circuit board
- High surge current capability
- •Meet UL flammability classification 94V-0

Mechanical Data

- Polarity: Symbol marked on body
- Mounting position: Any

Applications

 General purpose use in AC/DC bridge full wave rectification, for SMPS, lighting ballaster, adapter, etc.



Package Outline Dimensions in Inches (Millimeters)

Maximum Ratings and Electrical Characteristics

Rating at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz, resistive or inductive load.

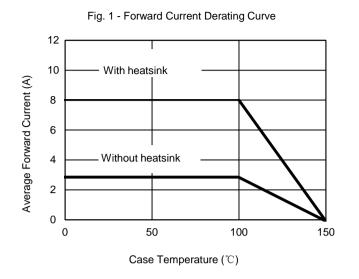
For capacitive load, derate current by 20%.

Characteristic	Symbol	GBU8005	GBU801	GBU802	GBU804	GBU806	GBU808	GBU810	Unit
Maximum Repetitive Peak Reverse Voltage	VRRM	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	VRMS	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	VDC	50	100	200	400	600	800	1000	V
Maximum Average Forward (with heatsink Note 2)	Lana	8.0							А
Rectified Current @ Tc=100°C (without heatsink)	I(AV)	2.8							
Peak Forward Surge Current, 8.3mS Single Half Sine-Wave,	IFSM	175							А
Superimposed on Rated Load (JEDEC Method)	IFSM								
I ² t Rating for Fusing (t<8.3mS)	l ² t	127.1							A ² s
Peak Forward Voltage per Diode at 4A DC	VF	1.0							V
Maximum DC Reverse Current at Rated @TJ=25℃	l _R	5.0							μА
DC Blocking Voltage per Diode @TJ=125℃	IK	500							
Typical Junction Capacitance per Diode (Note1)	CJ	50						pF	
Typical Thermal Resistance to case (with heatsink (Note2))	Rejc	2							°C/W
Operating Junction Temperature Range	TJ	-55 to +150							$^{\circ}$
Storage Temperature Range	Тѕтс	-55 to +150							$^{\circ}$
	-	-							

Notes: 1. Measured at 1.0 MHz and applied reverse voltage of 4.0V DC.

- 2.Device mounted on 75mm*75mm*1.6mm Cu plate heatsink.
- 3. The typical data above is for reference only





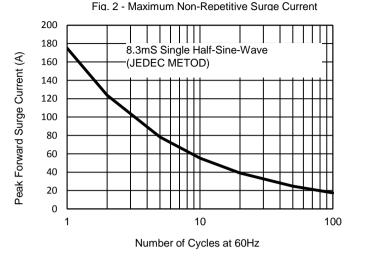


Fig. 3 - Typical Reverse Characteristics 1000 Instantaneous Reverse Current (uA) T_J=150° C 100 T_J=125° C T_J=100° C 10 TJ=75° C 1 TJ=25° С 0.1 40 80 20 60 100 Percent of Rated Peak Reverse Voltage (%)

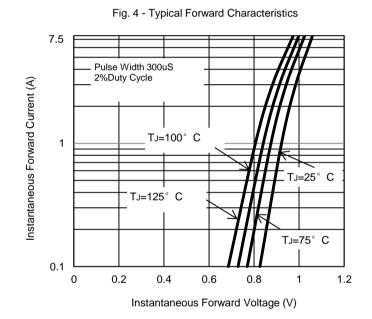
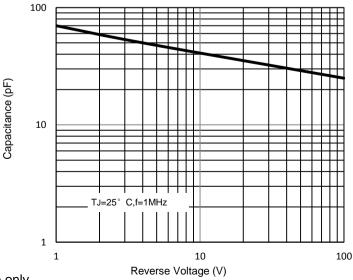


Fig. 5 - Typical Junction Capacitance



The curve above is for reference only.